



CMOS 16-BIT 3.3V TO 5V LEVEL SHIFTING TRANSCEIVER WITH 3-STATE OUTPUTS

IDT74ALVC164245

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{SR(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- VCCA = 2.7V to 3.6V
- VCCB = 5V ± 0.5V
- CMOS power levels (0.4 μ W typ. static)
- Rail-to-Rail output swing for increased noise margin
- Available in SSOP, TSSOP, and TVSOP packages

DESCRIPTION:

This 16-bit 3.3V to 5V level shifting transceiver is manufactured using advanced dual metal CMOS technology. The ALVC164245 contains two separate supply rails; B port has VCCB, which is set at 5V, and A port has VCCA, which is set to operate at 3.3V. This allows for translation from a 3.3V to 5V environment and vice-versa. This device is designed for asynchronous communication between data buses.

The ALVC164245 has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

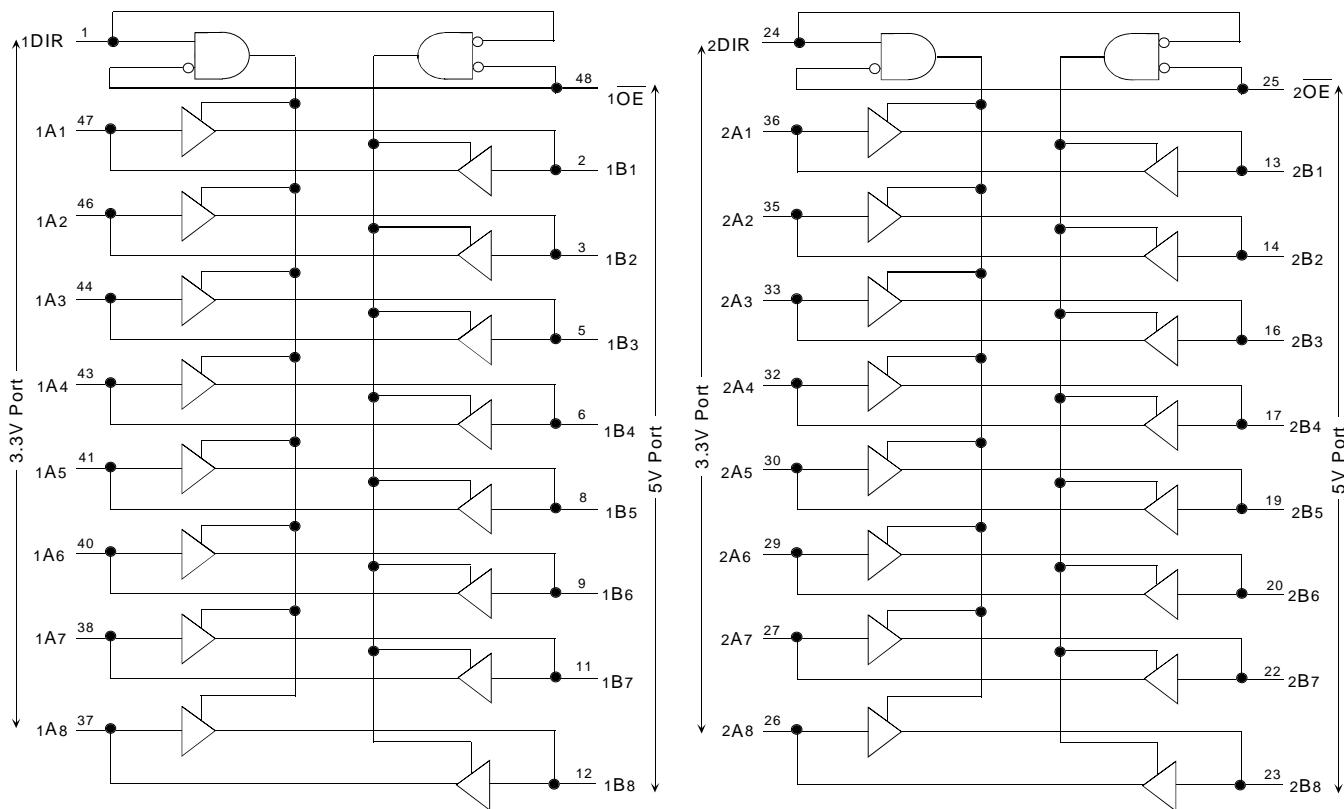
DRIVE FEATURES:

- High Output Drivers: ±24mA
- Suitable for heavy loads

APPLICATIONS:

- Mixed 3.3V and 5V High Speed Systems
- 5V PCI Interface to 3.3V PC Bus Structures
- Telecommunication Legacy Systems with transitions from 5V to 3.3V

FUNCTIONAL BLOCK DIAGRAM



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INDUSTRIAL TEMPERATURE RANGE

OCTOBER 1999

PIN CONFIGURATION

1DIR	1	48	1OE
1B1	2	47	1A1
1B2	3	46	1A2
GND	4	45	GND
1B3	5	44	1A3
1B4	6	43	1A4
(5V) VCCB	7	42	VCCA (3.3V)
1B5	8	41	1A5
1B6	9	40	1A6
GND	10	39	GND
1B7	11	38	1A7
1B8	12	37	1A8
2B1	13	36	2A1
2B2	14	35	2A2
GND	15	34	GND
2B3	16	33	2A3
2B4	17	32	2A4
(5V) VCCB	18	31	VCCA (3.3V)
2B5	19	30	2A5
2B6	20	29	2A6
GND	21	28	GND
2B7	22	27	2A7
2B8	23	26	2A8
2DIR	24	25	2OE

SSOP/ TSSOP/ TVSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +6	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to +6	V
TSTG	Storage Temperature	-65 to +150	°C
IOUT	DC Output Current	-50 to +50	mA
IIK	Continuous Clamp Current, VI < 0 or VI > Vcc	±50	mA
IOK	Continuous Clamp Current, VO < 0	-50	mA
Icc	Continuous Current through each Vcc or GND	±100	mA
Iss			

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Vcc terminals.
- All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz, VCCA = 3.3V)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
CIN	A Port Input Capacitance	VIN = 0V	6.5	—	pF
Cl/O	A Port I/O Capacitance	VIN = 0V	8.5	—	pF

NOTE:

- As applicable to the device type.

CAPACITANCE (TA = +25°C, F = 1.0MHz, VCCB = 5V)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
CIN	B Port Input Capacitance	VIN = 0V	6.5	—	pF
Cl/O	B Port I/O Capacitance	VIN = 0V	6.5	—	pF

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
xOE	Output Enable Inputs (Active LOW)
xDIR	Direction Output Controls
xAx	Port A Inputs or 3-State Outputs
xBx	Port B Inputs or 3-State Outputs

FUNCTION TABLE (EACH 8-BIT SECTION)⁽¹⁾

Inputs		Outputs
xOE	xDIR	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

NOTE:

- H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Don't Care
- Z = High Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE (B PORT)⁽¹⁾

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CCB} = 4.5V to 5.5V		2	—	—	V
V _{IL}	Input LOW Voltage Level	V _{CCB} = 4.5V to 5.5V		—	—	0.8	V
I _{IH}	Input HIGH Current	V _{CCB} = 5.5V	V _I = V _{CC}	—	—	±5	µA
I _{IL}	Input LOW Current	V _{CCB} = 5.5V	V _I = GND	—	—	±5	µA
I _{OZH}	High Impedance Output Current (3-State Output pins)	V _{CCB} = 5.5V	V _O = V _{CC}	—	—	±10	µA
I _{OZL}			V _O = GND	—	—	±10	
V _H	Input Hysteresis	V _{CCB} = 4.5V		—	100	—	mV
I _{CCL} I _{CH} I _{CCZ}	Quiescent Power Supply Current	V _{CCB} = 5.5V V _{IN} = GND or V _{CCB}		—	0.1	40	µA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at 3.4V, other inputs at V _{CCB} or GND		—	—	750	µA

NOTES:

1. V_{CCA} = 2.7V to 3.6V.
2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE (A PORT)^(1,2)

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CCA} = 2.7V to 3.6V		2	—	—	V
V _{IL}	Input LOW Voltage Level	V _{CCA} = 2.7V to 3.6V		—	—	0.8	V
I _{IH}	Input HIGH Current	V _{CCA} = 3.6V	V _I = V _{CC}	—	—	±5	µA
I _{IL}	Input LOW Current	V _{CCA} = 3.6V	V _I = GND	—	—	±5	µA
I _{OZH}	High Impedance Output Current (3-State Output pins)	V _{CCA} = 3.6V	V _O = V _{CC}	—	—	±10	µA
I _{OZL}			V _O = GND	—	—	±10	
V _H	Input Hysteresis	V _{CCA} = 3.3V		—	100	—	mV
I _{CCL} I _{CH} I _{CCZ}	Quiescent Power Supply Current	V _{CCA} = 3.6V V _{IN} = GND or V _{CCA}		—	0.1	40	µA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at V _{CCA} - 0.6V, other inputs at V _{CCA} or GND		—	—	750	µA

NOTES:

1. V_{CCB} = 5V ± 0.5V.
2. Control inputs xDIR, \overline{CE} are supplied from V_{CCA}.
3. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS, $V_{CCA} = 3.3V \pm 0.3V$ (A PORT)

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage (B Port to A Port)	V _{CCA} = 2.7V to 3.6V	I _{OH} = - 0.1mA	V _{CCA} = 0.2	—	V
		V _{CCA} = 2.7V	I _{OH} = - 12mA	2.2	—	
		V _{CCA} = 3V		2.4	—	
		V _{CCA} = 3V	I _{OH} = - 24mA	2	—	
VOL	Output LOW Voltage (B Port to A Port)	V _{CCA} = 2.7V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		V _{CCA} = 2.7V	I _{OL} = 12mA	—	0.4	
		V _{CCA} = 3V	I _{OL} = 24mA	—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range.
 $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$; V_{CCA} = 3.3V ± 0.3V.

OUTPUT DRIVE CHARACTERISTICS, $V_{CCB} = 5V \pm 0.5V$ (B PORT)

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage (A Port to B Port)	V _{CCB} = 4.5V	I _{OH} = - 0.1mA	4.3	—	V
		V _{CCB} = 5.5V		5.3	—	
		V _{CCB} = 4.5V	I _{OH} = - 24mA	3.7	—	
		V _{CCB} = 5.5V		4.7	—	
VOL	Output LOW Voltage (A Port to B Port)	V _{CCB} = 4.5V	I _{OL} = 0.1mA	—	0.2	V
		V _{CCB} = 5.5V		—	0.2	
		V _{CCB} = 4.5V	I _{OL} = 24mA	—	0.55	
		V _{CCB} = 5.5V		—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range.
 $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$; V_{CCB} = 5V ± 0.5V.

OPERATING CHARACTERISTICS, TA = 25°C

Symbol	Parameter	Test Conditions	VCCA = 3.3V, VCCB = 5V	Unit
			Typical	
CPD	Power Dissipation Capacitance, Outputs enabled (A port or B port)	CL = 0pF, f = 10Mhz	56	pF
CPD	Power Dissipation Capacitance, Outputs disabled (A port or B port)		6	

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	VCCB = 5V ± 0.5V				Unit	
		VCCA = 2.7V		VCCA = 3.3V ± 0.3V			
		Min.	Max.	Min.	Max.		
tPLH tPHL	Propagation Delay xAx to xBx	—	5.9	1	5.8	ns	
tPLH tPHL	Propagation Delay xBx to xAx	—	6.7	1.2	5.8	ns	
tPZH tPZL	Output Enable Time xOE to xBx	—	9.3	1	8.9	ns	
tPZH tPZL	Output Enable Time xOE to xAx	—	10.2	2	9.1	ns	
tPHZ tPLZ	Output Disable Time xOE to xBx	—	9.2	2.1	9.4	ns	
tPHZ tPLZ	Output Disable Time xOE to xAx	—	9	2.9	8.6	ns	

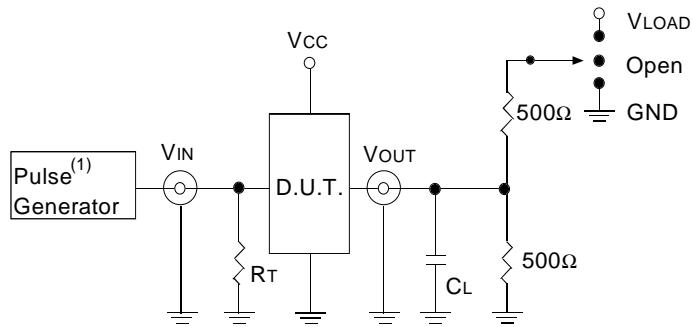
NOTE:

1. See TEST CIRCUITS AND WAVEFORMS. TA = - 40°C to + 85°C.

TEST CIRCUITS AND WAVEFORMS FOR $V_{CCA} = 3.3V \pm 0.3V$ AND $V_{CCA} = 2.7V$

TEST CONDITIONS

Symbol	$V_{CCA} = 3.3V \pm 0.3V$	$V_{CCA} = 2.7V$	Unit
V_{LOAD}	6	6	V
V_{IH}	3	3	V
V_T	1.5	1.5	V
V_{LZ}	300	300	mV
$V_{OH} - V_{HZ}$	300	300	mV
C_L	50	50	pF



Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

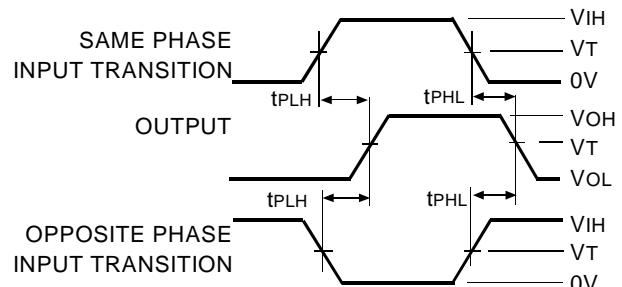
RT = Termination resistance: should be equal to Z_{out} of the Pulse Generator.

NOTE:

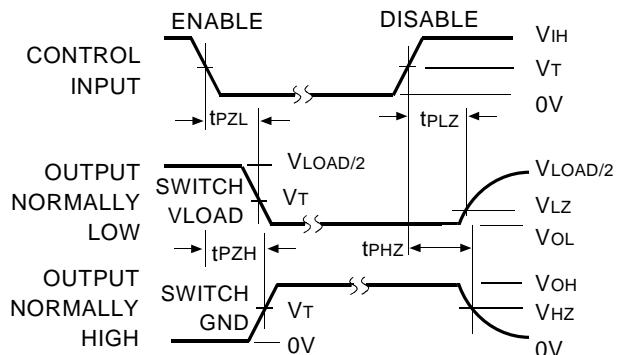
1. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_f \leq 2.5\text{ns}$; $t_r \leq 2.5\text{ns}$.

SWITCH POSITION

Test	Switch
Disable Low Enable Low	V_{LOAD}
Disable High Enable High	GND
All Other Tests	Open



Propagation Delay



Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

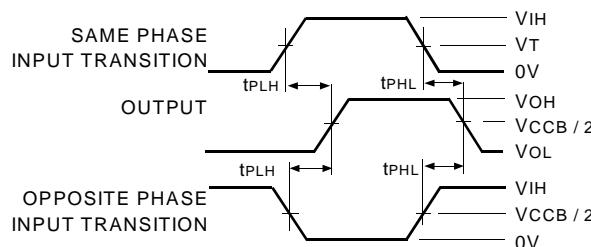
TEST CIRCUITS AND WAVEFORMS FOR $V_{CCB} = 5V \pm 0.5V$

TEST CONDITIONS (USE V_{CCA} TEST CIRCUIT)

Symbol	$V_{CCB}^{(1)} = 5V \pm 0.2V$	Unit
V_{LOAD}	$2 \times V_{CCB}$	V
V_{IH}	2.7	V
V_T	1.5 or $V_{CCB}/2$	V
V_{LZ}	20% of V_{CCB}	mV
V_{HZ}	80% of V_{CCB}	mV
C_L	50	pF

NOTE:

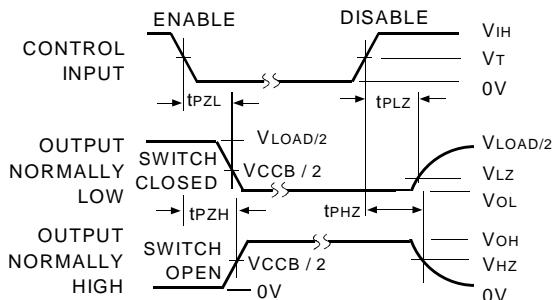
- Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_f \leq 2.5\text{ns}$; $t_r \leq 2.5\text{ns}$.



Propagation Delay

NOTES:

- For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



Enable and Disable Times

NOTE:

- Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

ORDERING INFORMATION

IDT	XX	ALVC	X	XX	XXX	XX	
Temp. Range	Bus-Hold	Family		Device Type		Package	
						PV	Shrink Small Outline Package
						PA	Thin Shrink Small Outline Package
						PF	Thin Very Small Outline Package
					245		16-Bit 3.3V to 5V Level Shifting Transceiver with 3-State Outputs
					164		Double-Density with Resistors, ±24mA
					Blank		No Bus-Hold
					74		–40°C to +85°C



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